



DMN3033LSDQ

Product Summary

| BV _{DSS} | Rds(on) Max | I _D Max T _A = +25°C |
|-------------------|------------------------------|----------------------------------------------|
| | 20mΩ @ V _{GS} = 10V | 6.9A |
| 30V | $27m\Omega @ V_{GS} = 4.5V$ | 5.8A |

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN3033LSDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

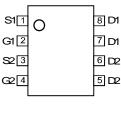
https://www.diodes.com/quality/product-definitions/

Mechanical Data

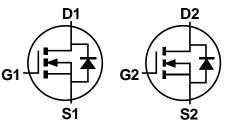
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.072grams (Approximate)



Top View







N-Channel MOSFET

N-Channel MOSFET

Ordering Information (Note 4)

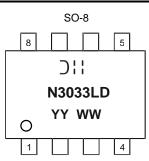
| Part Number | | Case | Packaging | | |
|--------------------------------------------------------------------------------------------------------------------------------|--|------|-------------------|--|--|
| DMN3033LSDQ-13 | | SO-8 | 2,500/Tape & Reel | | |
| Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. | | | | | |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



⊃¦¦ = Manufacturer's Marking N3033LD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 20 = 2020) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|-------------------------------|-----------------|--------------------------------------------------|------------------|------------|------|
| Drain-Source Voltage | | | VDSS | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Drain Current (Note 5) | Steady State | T _A = +25°C T _A = +70°C | ID | 6.9 5.8 | А |
| Pulsed Drain Current (Note 6) | | | ldм | 30 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|-----------------------------------------|----------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 2 | W |
| Thermal Resistance, Junction to Ambient | Reja | 62.5 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

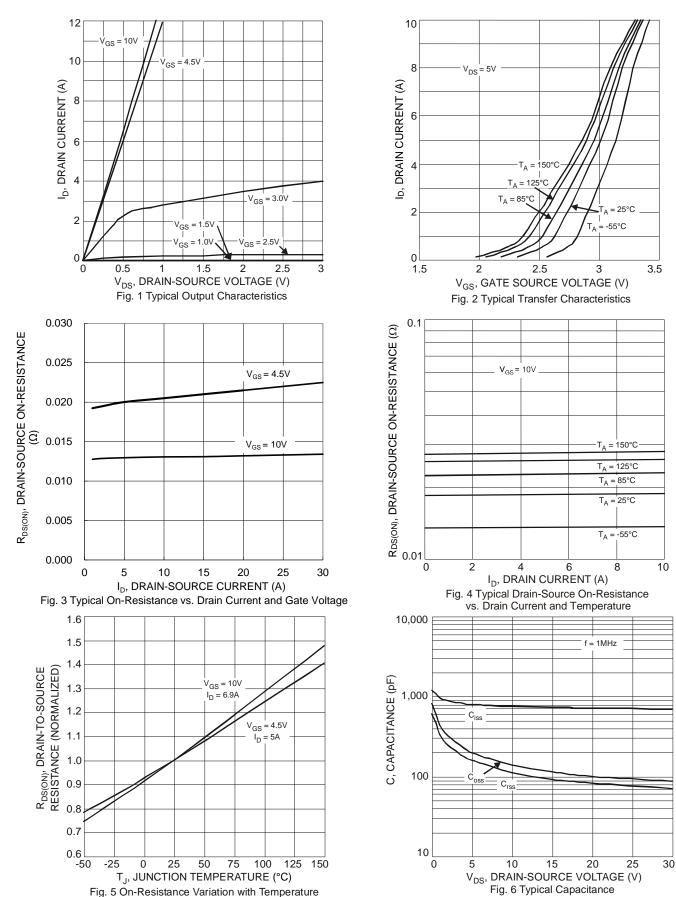
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|------------------------------------|---------------------|-----|------|----------|------|---------------------------------------------------------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BVDSS | 30 | _ | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | IDSS | _ | — | 100 | nA | $V_{DS} = 30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | lass | _ | _ | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| Gale-Source Leakage | lgss | | _ | 1 | μA | $V_{GS} = \pm 25 V$, $V_{DS} = 0 V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | VGS(TH) | 1 | | 2.1 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Desser | | 13 | 20 27 | mΩ | VGS = 10V, ID = 6.9A | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 22 | | | $V_{GS} = 4.5V, I_D = 5A$ | |
| Forward Transconductance | g fs | _ | 7 | _ | S | V _{DS} =5V, I _D = 6.9A | |
| Diode Forward Voltage (Note 7) | V _{SD} | 0.5 | _ | 1.2 | V | $V_{GS} = 0V, I_S = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | | 725 | _ | pF | V _{DS} = 15V, V _{GS} = 0V f = 1MHz | |
| Output Capacitance | Coss | _ | 114 | _ | pF | | |
| Reverse Transfer Capacitance | Crss | | 92 | _ | pF | | |
| Gate Resistance | R _G | | 0.89 | _ | Ω | $V_{GS} = 0V$, $V_{DS} = 0V$, $f = 1MHz$ | |
| SWITCHING CHARACTERISTICS (Note 8) | | | | | | | |
| Total Gate Charge | Qg | | 6.4 | | nC | $V_{GS} = 4.5V, V_{DS} = 15V, I_{D} = 5A$ | |
| ÷ | αg | | 13 | | _ | VGS = 10V, VDS = 15V, ID = 6.9A | |
| Gate-Source Charge | Qgs | — | 1.9 | | nC | VGS = 4.5V, VDS = 15V, ID = 6.9A | |
| Gate-Drain Charge | Q _{gd} | _ | 3.2 | _ | nC | $V_{GS} = 4.5V, V_{DS} = 15V, I_D = 6.9A$ | |
| Turn-On Delay Time | td(on) | _ | 11 | — | ns | | |
| Turn-On Rise Time | t _R | _ | 7 | _ | ns | $V_{DD} = 15V, V_{GS} = 10V,$ | |
| Turn-Off Delay Time | tD(OFF) | _ | 63 | _ | ns | $R_D = 1.8\Omega, R_G = 6\Omega$ | |
| Turn-Off Fall Time | tF | _ | 30 | | ns | | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Notes: 5. Device mounted on 2 oz. Copper pads on FR-4 PCB with $R_{\theta JA} = 62.5^{\circ}C/W$.

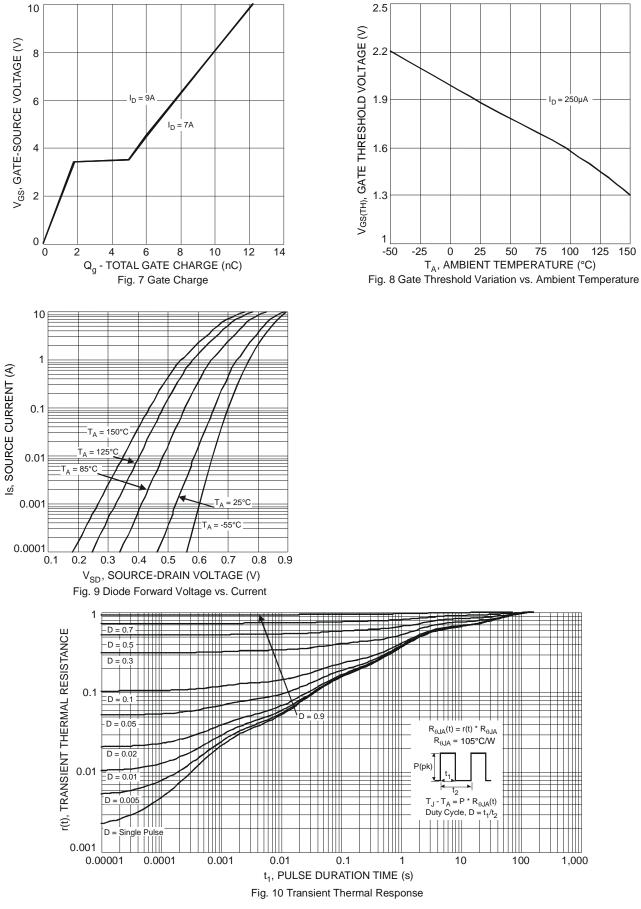
Belse width ≤10µS, Duty Cycle ≤1%.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.







150

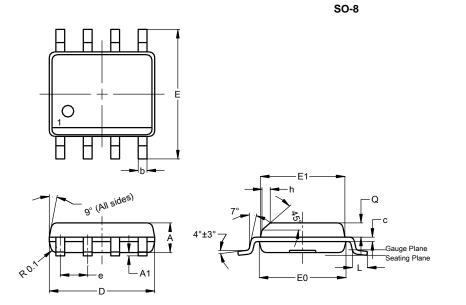


4 of 6



Package Outline Dimensions

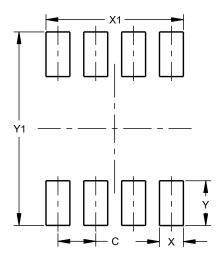
Please see http://www.diodes.com/package-outlines.html for the latest version.



| SO-8 | | | | | |
|----------------------|------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.40 | 1.50 | 1.45 | | |
| A1 | 0.10 | 0.20 | 0.15 | | |
| b | 0.30 | 0.50 | 0.40 | | |
| C | 0.15 | 0.25 | 0.20 | | |
| D | 4.85 | 4.95 | 4.90 | | |
| Е | 5.90 | 6.10 | 6.00 | | |
| E1 | 3.80 | 3.90 | 3.85 | | |
| E0 | 3.85 | 3.95 | 3.90 | | |
| e | | | 1.27 | | |
| h | | | 0.35 | | |
| L | 0.62 | 0.82 | 0.72 | | |
| Q | 0.60 | 0.70 | 0.65 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| С | 1.27 | | |
| Х | 0.802 | | |
| X1 | 4.612 | | |
| Y | 1.505 | | |
| Y1 | 6.50 | | |

package-outlines.html for t



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))